

MB05S-MB10S

Silicon Bridge Rectifiers

VOLTAGE RANGE: 50 --- 1000 V CURRENT: 0.5 A

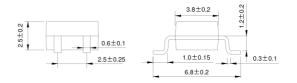
MBS

Features

- This series is UL recognized under Component Index, file number E239431
- ♦ Glass passivated chip junctions
- Plastic materrial has U/L flammability classification 94V-O
- ♦ High surge overload rating: 35A peak
- ♦ Saves space on printed circuit boards
- ♦ High temperature soldering quaranteed:
- ♦ 260°C/10 seconds at 5 lbs. (2.3kg) tension

Mechanical Data

- ♦ Case: Molded plastic body over passivated junctions
- ♦ Terminals: Plated leads solderable per MIL-STD-750, Method 2026
- Polarity: Polarity symbols marked on body
 Dimensions in inches and (millimeters)
- ♦ Mounting Position: Any
- ♦ Weight: 0.0078 ounce, 0.22 gram



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		MB05S	MB1S	MB2S	MB4S	MB6S	MB8S	MB10S	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	٧
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forw ard output current @T _A =25 °C	I _{F(AV)}	0.5						А	
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load	I _{FSM}	35.0							А
Maximum instantaneous forw ard voltage @ 0.4 A	V _F	1.0						V	
Maximum reverse current @T _A =25℃ at rated DC blocking voltage @T _A =100℃	I _R	5.0 0.5							μA mA
Typical junction capacitance per leg (NOTE 3)	C_{J}	13						pF	
Typical thermal resistance per leg (NOTE 1) (NOTE 2)	$R_{_{ heta}}$ JA $R_{_{ heta}}$ JL	85 20						°C/W	
Operating junction temperature range	TJ	- 55 + 150							Č
Storage temperature range	T _{STG}		- 55 + 150						Č

NOTES: (1) On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3mm) pads

⁽²⁾ On aluminum substrate P.C.B. with an area of $0.8" \times 0.8"$ (20 x 20mm) mounted on $0.05 \times 0.05"$ (1.3 x 1.3mm) solder pad

⁽³⁾ Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts



AVERAGE FORWARD CURRENT, AMPERES

INSTANTANEOUS FORWARD CURRENT,

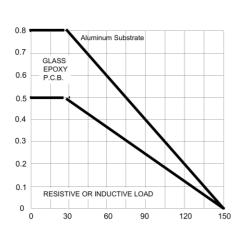
AMPERES

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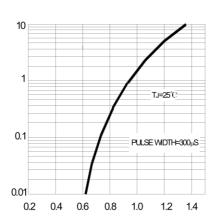
Ratings AND Charactieristic Curves

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT



AMBIENT TEMPERATURE, ℃

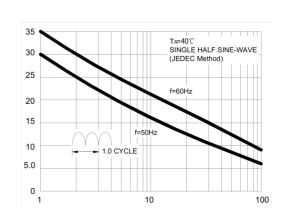
FIG.3 - TYPICAL FORWARD VOLTAGE **CHARACTERISTICS PER LEG**



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT PER LEG

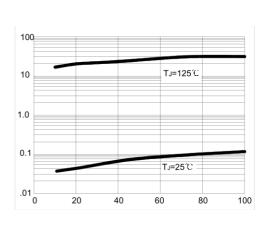
PEAK FORWARD SURGE CURRENT, **AMPERES**



NUMBER OF CYCLES AT 50/60Hz

FIG.4 - TYPICAL REVERSE CHARACTERISTIC

INSTANTANEOUS REVERSE CURRENT, MICRO AMPERES

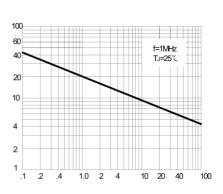


PERCENT OF RATED PEAK REVERSE VOLTAGE,%

FIG.5 - TYPICAL JUNCTION CAPACITANCE PER ELEMENT

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CAPACITANCE,



REVERSE VOLTAGE, VOLTS